


Cite this: *RSC Adv.*, 2021, 11, 17985

# Stabilizing an ultrathin MoS<sub>2</sub> layer during electrocatalytic hydrogen evolution with a crystalline SnO<sub>2</sub> underlayer†

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Amorphous MoS<sub>2</sub> has been investigated abundantly as a catalyst for hydrogen evolution. Not only its performance but also its chemical stability in acidic conditions have been reported widely. However, its adhesion has not been studied systematically in the electrochemical context. The use of MoS<sub>2</sub> as a lubricant is not auspicious for this purpose. In this work, we start with a macroporous anodic alumina template as a model support, add an underlayer of SnO<sub>2</sub> to provide electrical conduction and adhesion, then provide the catalytically active, amorphous MoS<sub>2</sub> material by atomic layer deposition (ALD). The composition, morphology, and crystalline or amorphous character of all layers are confirmed by spectroscopic ellipsometry, X-ray photoelectron spectroscopy, grazing incidence X-ray diffractometry, scanning electron microscopy and energy dispersive X-ray spectroscopy. The electrocatalytic water reduction performance of the macroporous AAO/SnO<sub>2</sub>/MoS<sub>2</sub> electrodes, quantified by voltammetry, steady-state chronoamperometry and electrochemical impedance spectroscopy, is improved by annealing the SnO<sub>2</sub> layer prior to MoS<sub>2</sub> deposition. Varying the geometric parameters of the electrode composite yields an optimized performance of 10 mA cm<sup>-2</sup> at 0.22 V overpotential, with a catalyst loading of 0.16 mg cm<sup>-2</sup>. The electrode's stability is contingent on SnO<sub>2</sub> crystallinity. Amorphous SnO<sub>2</sub> allows for a gradual dewetting of the originally continuous MoS<sub>2</sub> layer over wide areas. In stark contrast to this, crystalline SnO<sub>2</sub> maintains the continuity of MoS<sub>2</sub> until at least 0.3 V overpotential.

Received 2nd February 2021  
Accepted 5th May 2021

DOI: 10.1039/d1ra00877c

rsc.li/rsc-advances

## Introduction

With increasing contributions of renewable, inherently intermittent, energy sources to the energy mix, finding a way to store excess electrical power becomes crucial to the success of the energy transition.<sup>1,2</sup> Electrolysis represents a prominent solution, which stores electrical power in chemical form, as dihydrogen. This clean fuel affords high energy storage density and can be transported and converted back to electrical energy in fuel cells.<sup>3,4</sup> To maximize the energy efficiency of the whole

storage and release cycle, the electrolysis of water must be performed at low overpotentials, and therefore, be effectively catalyzed on both electrodes. For the hydrogen evolution reaction (HER), noble metals such as Pt or its alloys still offer the lowest overpotentials.<sup>5–7</sup> Drawbacks are, however, low noble-element abundance and high costs. Thus, the search for alternative catalyst materials is of significant interest.<sup>8</sup>

MoS<sub>2</sub> is considered as a highly interesting potential alternative to noble metals as an electrocatalyst for H<sub>2</sub> evolution. It has been widely reported as being chemically stable in acidic conditions, but its (equally important) adhesion to electrode substrates has not been studied systematically.<sup>9–12</sup> Catalysis at the surface of this layered transition metal dichalcogenide<sup>13</sup> occurs on S vacancies at the edges of individual sheets, which feature a H adsorption free energy  $\Delta G_{\text{ads}}$  comparable to noble metals such as Pt.<sup>14–16</sup> The basal planes of the crystal are not involved in catalysis, so that amorphous forms of MoS<sub>2</sub> exhibiting a high density of Mo defects and disulfide sites offer highest HER activity.<sup>17–19</sup>

The electrical properties of amorphous MoS<sub>2</sub> (a-MoS<sub>2</sub>), however, are mediocre and hinder its scalable application in hydrogen production. This impediment becomes problematic when non-planar electrode substrates are used. Such electrodes offering high

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† Electronic supplementary information (ESI) available. See DOI: 10.1039/d1ra00877c

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specific surface area usually serve to increase macroscopically defined current densities in electrochemical energy conversion devices and feature porous surface. In that perspective, MoS<sub>2</sub> has already been deposited on carbon nanospheres,<sup>20,21</sup> CdS nanorods,<sup>22,23</sup> porous metallic MoO<sub>3</sub>,<sup>24</sup> and titanium oxide nanotube arrays.<sup>9,25</sup> In those examples, the current must be transported by an electrically conductive substrate since long distances along thin a-MoS<sub>2</sub> layers would cause too high ohmic resistance losses.

The study of transport and surface limitations at nanoporous electrode surfaces, and the optimization of geometry towards electrocatalytic turnover, can be performed at a geometrically perfect model system presented by ‘anodized’ aluminum oxide (as the substrate) coated (with the functional layer) by atomic layer deposition. Anodized aluminum oxide (‘anodic alumina’ or AAO) made by electrochemical oxidation of the metal delivers ordered arrays of straight, parallel and cylindrical pores the diameter and length of which can be adjusted accurately and varied systematically (on the scale of 10–500 nm and of 0.5–100 μm, respectively).<sup>26</sup> To coat substrates with pores of such high aspect ratios, atomic layer deposition (ALD) has emerged as a key technique. Its ability to coat nanoporous substrates with a-MoS<sub>2</sub> in a homogeneous, conformal manner has been demonstrated.<sup>9,27</sup> If the electrically insulating AAO is used as a substrate, however, the limited electrical conductivity of a-MoS<sub>2</sub> coatings of ≤20 nm thickness must be compensated for by an appropriate underlying layer.<sup>28,29</sup> We propose SnO<sub>2</sub> in this function, since it has proven to be advantageous for this purpose.<sup>30,31</sup> Its deposition *via* ALD is well established<sup>32</sup> and it features a high charge carrier density and overall conductivity.<sup>33</sup> Additionally, its conduction band is located at about −4.5 eV (vs. *E*<sub>vac</sub>) and matches the respective band of MoS<sub>2</sub> quite well.<sup>34</sup> The goal of this study is to establish the conditions in which a macroporous AAO/SnO<sub>2</sub>/a-MoS<sub>2</sub> electrocatalyst model system is stable. Limitations to stability are defined by MoS<sub>2</sub> itself and SnO<sub>2</sub>, the Pourbaix diagram of which indicates cathodic corrosion in acidic media.<sup>35</sup> This corrosion can be prevented by the a-MoS<sub>2</sub> layer, if it is continuous and remains immobile and pinhole-free during electrocatalytic turnover. We find that the most important aspect is the crystallinity of the SnO<sub>2</sub> coating, which can fix a-MoS<sub>2</sub> and prevent degradation.

## Experimental

### Chemicals

Chemicals are of analytical reagent grade, were purchased from Sigma-Aldrich, Alfa Aesar, ABCR, Carl Roth, Fisher Chemicals or VWR and then used as received. The aluminum foils (99.99%) were purchased from Smart Membranes and for anodization purposes, water purified in a Millipore Direct-Q 3 system was used. Silicon (100) wafers with an approximately 200 nm thick oxide layer were acquired from Silicon Materials Inc. H<sub>2</sub>S (3% in N<sub>2</sub>) was purchased from Air Liquide (Germany), the molybdenum precursor Mo[N(Me)<sub>2</sub>]<sub>4</sub> was synthesized following a literature procedure.<sup>36</sup> Sn[N(Me)<sub>2</sub>]<sub>4</sub> was purchased from ABCR (Germany) in 99.99% purity. H<sub>2</sub>O<sub>2</sub> (30%) was purchased from Carl Roth. In our hands, the consumption of metal–organic ALD precursors is on the order of 1 g per 1000 cycles.

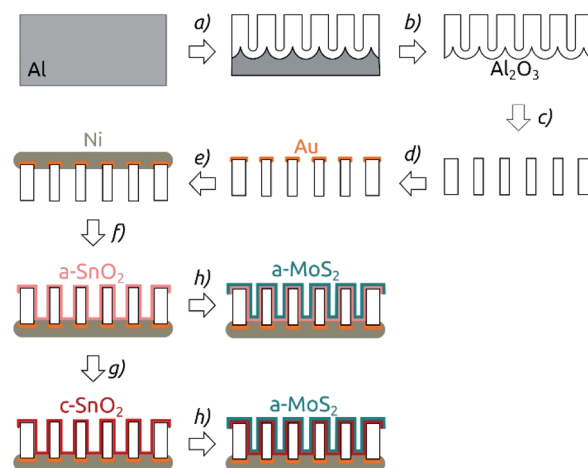


Fig. 1 Preparation procedure for nanostructured MoS<sub>2</sub> electrodes. The scheme shows the cross-section of the membrane. Note that at all steps of the scheme the membrane is still a continuous network, only traversed by pores. (a) Two-step anodization of Al foil. (b) Removal of the remaining Al substrate. (c) Barrier layer removal and pore widening in phosphoric acid. (d) Sputter coating of the Au contact. (e) Electroplating of a Ni backside contact. (f) ALD of SnO<sub>2</sub>. (g) Annealing (4 hours, 400 °C, N<sub>2</sub>). (h) ALD of MoS<sub>2</sub>.

### Preparation of nanostructured composite electrodes

The nanostructured electrodes were prepared in multiple steps as depicted in Fig. 1. Macroporous aluminum oxide membranes were obtained by a standard two-step anodization of aluminum (step (a) in Fig. 1).<sup>37</sup> The anodization was carried out using home-made four-opening PVC beakers, which held four pieces of Al foil at a time and which were screwed on thick copper plates (serving as the electrical contact). The beakers were filled with electrolyte and equipped with a stirrer including a counter-electrode consisting of Ag wires. Firstly, the aluminum plates were electro-polished in a cooled solution of perchloric acid in ethanol (1 : 3 v/v HClO<sub>4</sub>/EtOH) for 5 min under 20 V. Then the solution was rinsed away and the beakers were filled with a solution of 1 wt% H<sub>3</sub>PO<sub>4</sub> in Millipore water. After cooling to 0 °C using a Unichiller 012-MPC cooler, the Al plates were anodized under a constant voltage of 195 V for 23 h. This somewhat long first anodization duration is chosen so as to optimize the degree of order reached for the second anodization. The disordered porous Al<sub>2</sub>O<sub>3</sub> obtained was dissolved in a chromic acid solution (0.18 M CrO<sub>3</sub> in 6 wt% H<sub>3</sub>PO<sub>4</sub>) for 24 h at 45 °C. Then, a second anodization in 1 wt% H<sub>3</sub>PO<sub>4</sub> at 0 °C was performed for 3, 4, 6, or 8 h, yielding porous anodic alumina with various pore lengths (Fig. 1). Then, a solution of 0.7 M CuCl<sub>2</sub> in 10% HCl was used to remove the remaining Al underneath the pores (step (b) in Fig. 1). The oxide barrier layer on the extremity of the pores was removed (and the pores were simultaneously widened) by keeping the membranes in 10 wt% H<sub>3</sub>PO<sub>4</sub> for 37 min (step (c)). A 100 nm thick Au contact was DC-sputter coated on one side of the AAO membranes using a reactor from Torr International Inc. (step (d)). To obtain a thicker contact, this gold layer was then utilized as a cathode to galvanically plate a thick Ni layer. For this purpose, a diluted Watts electrolyte (0.57 M NiSO<sub>4</sub>, 95 mM NiCl<sub>2</sub>, 0.5 M H<sub>3</sub>BO<sub>3</sub>) was used and a potential of −2.3 V was applied for 5 h (Fig. 1e).



The deposition of  $\text{SnO}_2$  was performed by ALD in a commercial Gemstar-6 XT ALD reactor equipped with a Cobra BA 0100 C pump from Busch and with  $\text{N}_2$  as carrier gas (Fig. 1f).  $\text{Sn}[\text{N}(\text{Me})_2]_4$  and  $\text{H}_2\text{O}_2$  were used as precursors and maintained in stainless steel bottles at 65 °C and at room temperature, respectively. For the deposition, the chamber of the reactor was heated up to 150 °C. The tin precursor was pulsed for 0.6 s into the chamber, stayed in there for 50 s (exposure) and was subsequently pumped away by applying a continuous  $\text{N}_2$  flow and vacuum to the chamber for 90 s (purge). In the second half-cycle,  $\text{H}_2\text{O}_2$  was pulsed into the reactor with pulse, exposure and purge times of 0.6 s, 50 s and 70 s, respectively. 64 ALD cycles (c) yielded a deposition of 10 nm  $\text{SnO}_2$ , which corresponds to a growth per cycle (GPC) of approximately 1.6 Å per cycle.

After  $\text{SnO}_2$  was deposited, the membranes were optionally annealed in a furnace from Nabertherm under  $\text{N}_2$ -atmosphere (Fig. 1g). The temperature was ramped up over 5 h to the target temperature of 400 °C, which was kept for 4 h. The samples were then cooled down to room temperature over 8 h.

On top of the annealed tin oxide layer,  $\text{MoS}_2$  was deposited by atomic layer deposition (ALD) in a home-built hot-wall reactor equipped with a Cobra BA 0100 C pump from Busch and with  $\text{N}_2$  as the carrier gas (step (h) in Fig. 1).  $\text{Mo}[\text{N}(\text{Me})_2]_4$  and  $\text{H}_2\text{S}$  were used as molybdenum and sulfur sources and kept at 65 °C and at room temperature, respectively.<sup>27</sup> The deposition was carried out at 95 °C chamber temperature. For  $\text{Mo}[\text{N}(\text{Me})_2]_4$ , two pulses with a duration of 0.7 s (3 s apart), an exposure time of total 50 s and a purge time 60 s were used. The  $\text{H}_2\text{S}$  half-cycle was carried out with pulse, exposure and purge times of 0.2 s, 50 s and 60 s, respectively. 40 c yielded a deposition of 10 nm, corresponding to a GPC of approximately 2.5 Å per c. Thereafter, the samples were stored under  $\text{N}_2$  atmosphere until they were characterized electrochemically.

### Characterization

The layer thicknesses of semiconductors deposited by ALD were determined by spectroscopic ellipsometry (Sentech SENpro equipped with a tungsten halogen lamp) on Si (100) wafers, using the software SpectraRay 3. The deposited semiconductor crystal structures were characterized by measuring grazing incidence X-ray diffraction (GIXRD; incident angle: 0.6°) using a Bruker D8 Advance diffractometer equipped with a  $\text{Cu K}_\alpha$  radiation source and a LynxEye XE-T detector. Scanning electron microscopy (SEM) and energy-dispersive X-ray spectroscopy (EDX) were performed using either a JEOL JSM 6400 PC system implemented with a  $\text{LaB}_6$  cathode and SDD X-ray detector or a Carl Zeiss Gemini 500 field-emission instrument. X-ray photoelectron spectroscopy (XPS) was measured with a monochromatized Al  $\text{K}_\alpha$  source on a PHI Quantera II system. The core level spectra obtained were evaluated using a Shirley background subtraction and Voigt functions (convolution of Lorentz and Gauss distributions) to fit individual peaks. The spectra were all calibrated to a C 1s binding energy position of 284.8 eV.

### Electrochemical studies

After being coated with  $\text{MoS}_2$ , the samples were cut into small pieces and glued onto copper plates with conductive double-

sided copper tape. Then, the sample pieces were covered with a mask made out of polyimide tape (Kapton®) featuring a laser-cut circular hole with a diameter of 2.0 mm. For the electrochemical measurements, a three-electrode setup featuring a Pt mesh counter electrode and a Ag/AgCl reference electrode (3 M NaCl, standard potential shifted  $-0.20$  V compared to the standard hydrogen electrode SHE) was used. Most of the measurements were carried out in a 0.1 M  $\text{H}_2\text{SO}_4$  solution, whereas 0.5 M  $\text{H}_2\text{SO}_4$  was used in a small of cases. All electrochemical measurements including cyclic voltammetry (CV), linear sweep voltammetry (LSV), electrochemical impedance spectroscopy (EIS) and steady state chronoamperometry were carried out at room temperature on Gamry Interface 1000 potentiostats. Cyclic voltammograms were measured at a scan rate of  $50 \text{ mV s}^{-1}$ . The onset potential for HER was hereby defined as the overpotential required to reach the threshold current density of  $10 \text{ mA cm}^{-2}$ . Chronoamperometric measurements were performed at different applied potentials for 1 h; the resulting average current density was determined by averaging over the last 30 min. Impedance spectroscopy was measured at a potential of  $-0.3$  V (vs. SHE) between 100 kHz and 0.02 Hz and the obtained data were fitted using the software Gamry Echem Analyst. The circuit model used accounts for a series resistance ( $R_u$ ) and an RC element characterizing the liquid/solid interface. This element is modelled *via* a charge transfer resistance  $R_{ct}$  connected in parallel with a constant-phase element  $Q_{ls}$ , characterized by the impedance  $Y$  and the capacitor ideality factor  $\alpha$  ( $\alpha = 1$  for an ideal capacitor) and which accounts for the electrochemical double layer.

## Results and discussion

### Preparation and characterization of AAO/ $\text{SnO}_2$ / $\text{MoS}_2$ composite electrodes

The general procedure for nanostructured  $\text{MoS}_2$  electrode preparation is summarized in Fig. 1. Macroporous AAO substrates are prepared by a two-step anodization of aluminum in phosphoric acid. The second anodization carried out for durations of 3 to 8 h results in pore lengths of 8.6 to 18.5  $\mu\text{m}$  as determined by cross-section scanning electron microscopy (SEM) (Fig. S1†). A pore diameter of  $\sim 380$  nm is achieved *via* subsequent pore widening through wet-chemical etching in phosphoric acid (Fig. 2a). One face of the porous samples is then conferred with a metal contact by sputter coating Au (100 nm), followed by electrodeposition of Ni using a Watts electrolyte. This results in a metallic contact of approximately 3  $\mu\text{m}$  thickness (Fig. S1†), which defines the backside of the electrode.

The nanostructured templates are then coated with  $\text{SnO}_2$  by ALD and optionally annealed at 400 °C for 4 h. This temperature is the minimal value needed to yield crystallization at a reasonable rate, and it is the maximum that our samples can tolerate without risking delamination of the Ni contact. In the final step, the substrates are coated with  $\text{MoS}_2$  *via* ALD. Spectroscopic ellipsometry and AFM step edge measurements performed on planar reference substrates confirm that a film thickness of around 10 nm is achieved with 40 cycles (c) of  $\text{MoS}_2$  ALD (Fig. S2†), as expected based on the published growth rate.<sup>9</sup>



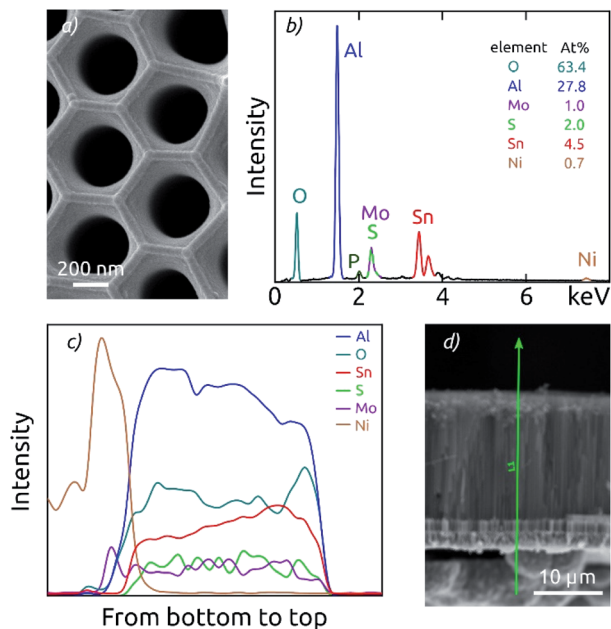


Fig. 2 Characterization of an AAO/SnO<sub>2</sub>/MoS<sub>2</sub> composite electrode with the highest pore length (18.5 μm). (a) Top-view SEM of the macroporous composite electrode. (b) EDX spectrum measured on the top of the sample. (c) Cross-section EDX analysis measured along the pores demonstrates the good uniformity of SnO<sub>2</sub> and MoS<sub>2</sub> coatings. The signals of the elements analyzed are arbitrarily scaled. (d) Scanning electron micrograph of the membrane in cross-section view, indicating the EDX measurement path as a green line.

Importantly, SEM investigation proves that the thin MoS<sub>2</sub> film on the AAO/SnO<sub>2</sub> substrate is perfectly continuous (Fig. 2a).

EDX analysis performed on the top face of the electrodes confirms the chemical composition of the full stack (Fig. 2b). The AAO template is manifested by the signals of O, Al and P (where P is due to phosphate incorporation into the alumina upon anodization).<sup>26,38</sup> The thin films deposited generate additional Mo and S signals in an atomic ratio of 1 : 2, as well as Sn peaks.

Cross-section EDX analysis demonstrates a good uniformity of the ALD coatings along the AAO pores of all lengths (Fig. 2c). EDX signals of Al and O are attributed to the AAO template and thus define the full sample thickness. In this section, fairly constant signals are also observed for the elements Mo, S and Sn, which are part of the ALD-grown films. Due to the spectral

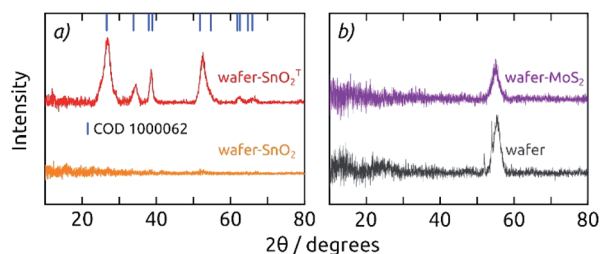


Fig. 3 (a) Grazing-incidence X-ray diffraction patterns of 20 nm thick SnO<sub>2</sub> layers on a Si(100) wafer, as deposited (orange) and annealed (T, red): annealing converts a-SnO<sub>2</sub> to c-SnO<sub>2</sub>. (b) Grazing-incidence X-ray diffraction patterns of 20 nm as-deposited MoS<sub>2</sub> on a Si(100) wafer (purple) compared to the bare wafer without coating (black).

overlap of the Mo L-line and the S K-line, the attribution of the signal intensity to each element exhibits some uncertainty. However, the sum of both signals is observed to be constant along the pore length. The presence of nickel contact is evident on one side of the sample. Altogether, the EDX results prove that both SnO<sub>2</sub> and MoS<sub>2</sub> form a continuous layer from the top to the bottom of the AAO pores, and successfully contact the nickel electrode.

Grazing incidence X-ray diffraction (GIXRD) of 20 nm thick films (SnO<sub>2</sub>, MoS<sub>2</sub>) deposited on Si(100) wafers (Fig. 3) indicates that both materials are amorphous as grown by ALD at low temperatures (a-SnO<sub>2</sub> and a-MoS<sub>2</sub>), which is in agreement with literature data for the ALD parameters applied here.<sup>27,32</sup> Here, we will only deal with amorphous MoS<sub>2</sub>, since its electrocatalytic properties are superior to those of crystalline MoS<sub>2</sub>. Tin(IV) oxide, however, crystallizes to cassiterite upon annealing at 400 °C for 4 h (c-SnO<sub>2</sub>, COD 1000062). XRD performed in regular Bragg–Brentano geometry on the functional electrodes confirms the formation of c-SnO<sub>2</sub>, with additional diffraction patterns for Ni and Al (COD 2102278, COD 2300250, Fig. S3†).

A highly surface-sensitive information is provided by XPS. The survey XPS spectrum of a AAO/c-SnO<sub>2</sub>/a-MoS<sub>2</sub> composite electrode features (after a short sputter treatment) only the expected signals of O, Sn, Mo and S (Fig. 4a). No signal for Al is

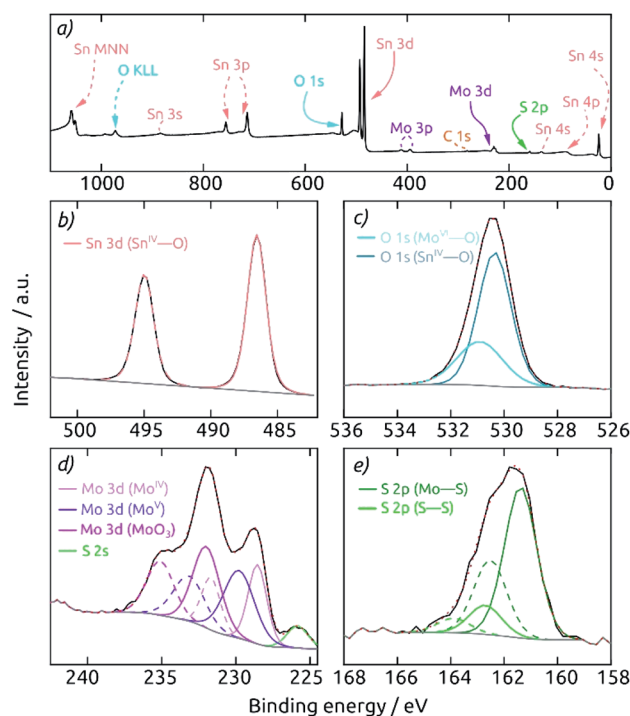


Fig. 4 X-ray photoelectron spectra of a macroporous AAO/c-SnO<sub>2</sub>/a-MoS<sub>2</sub> composite electrode after 30 s sputter-etching. The spectra were calibrated to a C 1s binding energy of 284.8 eV. (a) Survey spectrum showing the expected elements O, Sn, Mo, and S. Deconvolution of the core level spectra of the individual elements: (b) Sn 3d (here, a linear background was used to fit the data), (c) O 1s, (d) Mo 3d, and (e) S 2p. The deconvolution is shown with individual peaks in the element's characteristic color (doublet peaks in dashed lines). The measured spectrum is displayed in black, the background in gray and the envelope in red (dotted).



observed, indicating the absence of any pinholes across the c-SnO<sub>2</sub>/a-MoS<sub>2</sub> coating. The Sn 3d region (Fig. 4b) displays two peaks at 486.6 eV and 495.0 eV, corresponding to 3d<sub>5/2</sub> and 3d<sub>3/2</sub> signals of Sn<sup>IV</sup>, respectively. The O 1s spectrum reveals two different species at binding energies of 530.4 and 530.9 eV, which can be attributed to O bound to Sn and Mo, respectively (Fig. 4c). The deconvolution of the Mo 3d region is displayed in Fig. 4d. Here, three different Mo species contribute to the spectrum. MoS<sub>2</sub> is found with Mo 3d<sub>5/2</sub> and Mo 3d<sub>3/2</sub> peaks at 228.5 and 231.7 eV. A Mo<sup>V</sup> species, which is mainly found in edge states of nanocrystalline molybdenum sulfides,<sup>9,39</sup> is found at binding energies 229.8 and 233.1 eV for Mo 3d<sub>5/2</sub> and Mo 3d<sub>3/2</sub>, respectively. The doublet at 232.0 and 235.1 eV is characteristic of MoO<sub>3</sub> generated upon superficial oxidation of MoS<sub>2</sub> in contact with air. The S 2s peak overlaps with the Mo signals at 225.8 eV. The S 2p region, which is well separated from the rest, can be deconvoluted into two different S doublets (Fig. 4e). The main component is S present in MoS<sub>2</sub> with peaks at 161.4 and 162.5 eV for S 2p<sub>3/2</sub> and S 2p<sub>1/2</sub>, respectively. Peaks at higher binding energies of 162.7 and 163.9 eV correspond to the S 2p<sub>3/2</sub> and S 2p<sub>1/2</sub> contributions of the desired, catalytically active S-S bound edge species.<sup>9,40</sup>

### Electrochemical investigation: performance and stability

Cyclic voltammograms are used in the range of +0.2 V to −0.7 V (vs. SHE) to compare the cathodic hydrogen evolution performance of electrodes featuring various geometric parameters. The comparison of various pore lengths allows one to observe corresponding capacitive contributions, proving that the full surface of the pores is in contact with the electrolyte (Fig. S4a†). However, the pore length

does not improve the HER performance in any significant manner, indicating a transport limitation for the reaction (Fig. S4b†).

Fixing the pore length at 8.6 μm, the effect of electrocatalyst loading in the AAO/c-SnO<sub>2</sub>/a-MoS<sub>2</sub> system can be highlighted (Fig. 5a). Upon increasing the MoS<sub>2</sub> catalyst amount from 10 c ALD cycles (10 c) to 25 c and 40 c, the HER onset potential (defined as potential required to achieve a cathodic current density of −10 mA cm<sup>−2</sup>) is reduced from −0.45 V to −0.34 V and −0.31 V (vs. SHE), respectively. However, a catalyst layer thickness further increased to 75 c of MoS<sub>2</sub> delivers no significant additional benefit. If the steady-state current densities (averaged over 30 minutes, after a 60 minute electrolysis at each potential) are considered at various set potentials instead, a similar picture is obtained: 40 c of MoS<sub>2</sub> ALD represents the most efficient use of the catalyst. Electrochemical impedance spectroscopy performed at −0.3 V (vs. SHE) corroborates these results. The Nyquist plots and their fits are presented in Fig. 5c/d. The charge transfer resistance *R*<sub>ct</sub>, which is associated with the catalytic activity, decreases from 13 to 1.2 and 0.11 kΩ when the MoS<sub>2</sub> layer thickness increases from 10 to 25 and 40 c. Performance then plateaus out, with the thicker MoS<sub>2</sub> layer (75 c) still at 0.11 kΩ (3.5 Ω cm<sup>2</sup> for a circular sample of 2 mm diameter). Thus, a catalyst loading of 40 c MoS<sub>2</sub> is set as the standard for subsequent electrode characterization.

The annealed underlying SnO<sub>2</sub> layer proves to be beneficial the electrocatalytic activity (Fig. 6). Both the CV curves and steady-state current density values at different applied potentials exhibit the best electrochemical performance for the AAO/c-SnO<sub>2</sub>/a-MoS<sub>2</sub> configuration as compared to all other reference samples, with an HER onset potential of −0.31 V (vs. SHE). The improved performance with c-SnO<sub>2</sub> as compared with a-SnO<sub>2</sub> can be due to either the increased surface area generated by a rougher crystalline underlayer or the improved electrical transport characteristics offered by c-SnO<sub>2</sub> (or a combination thereof). The limiting property of electrical transport along the elongated pore structure is substantiated by the linear (as opposed to exponential) shape of the voltammetry curves. It is

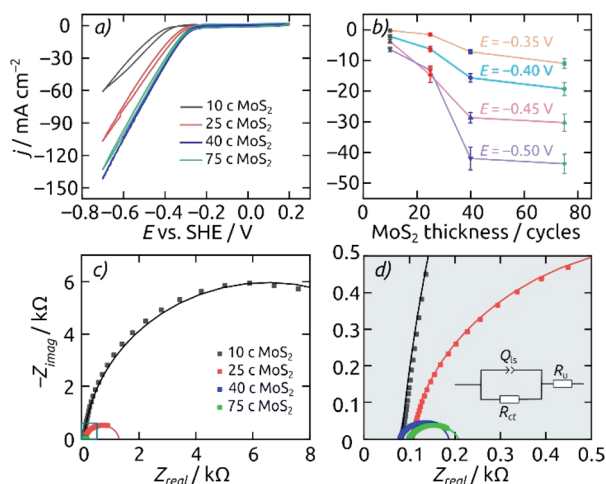


Fig. 5 Influence of different MoS<sub>2</sub> loadings on the electrocatalytic HER performance of AAO/c-SnO<sub>2</sub>/a-MoS<sub>2</sub> composite electrodes. All electrodes feature pore lengths of 8.6 μm and a 10 nm thick annealed layer of SnO<sub>2</sub>. (a) Cyclic voltammograms for catalyst loadings of 10 c (black), 25 c (red), 40 c (blue) and 75 c (green), from +0.2 V to −0.7 V (vs. SHE). Scan rate 50 mV s<sup>−1</sup>, step size 2 mV. (b) Average steady-state current densities at various applied potentials. (c) Nyquist plots for the same electrodes recorded at −0.3 V (vs. SHE). Fitted curves are displayed as solid lines. (d) Close-up of the EIS data near the origin and equivalent circuit model used for the fit. All measurements are performed with an electrode featuring a macroscopic area of 0.0314 cm<sup>2</sup> in 0.1 M H<sub>2</sub>SO<sub>4</sub> as the electrolyte.

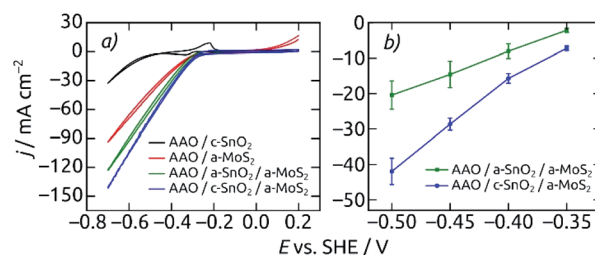
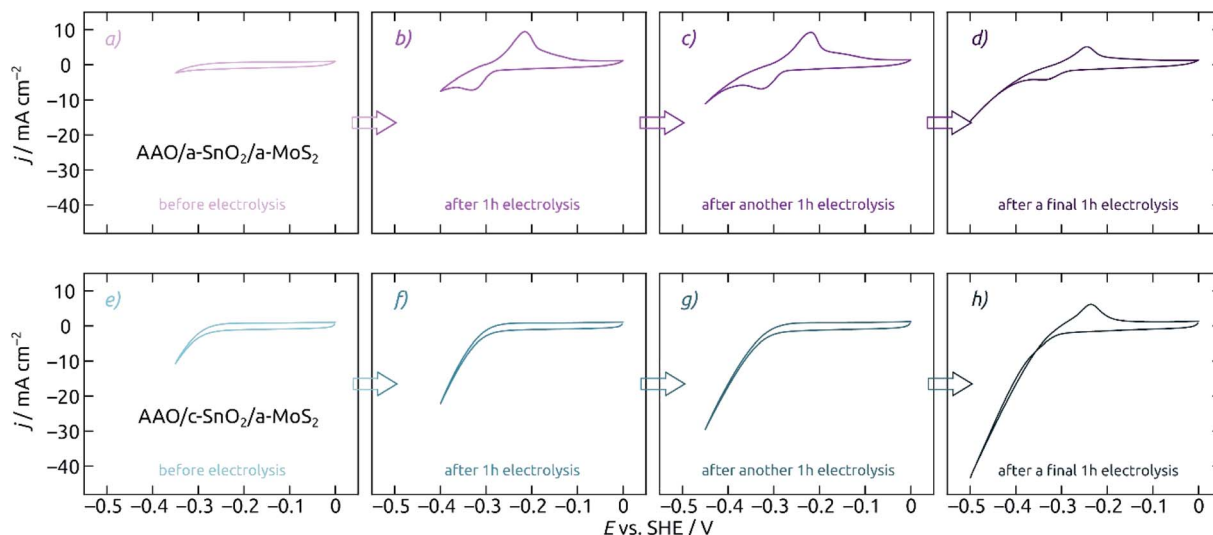


Fig. 6 Electrocatalytic performance for different electrode compositions. Macroporous AAO coated with only c-SnO<sub>2</sub> (black) and only MoS<sub>2</sub> (red) are compared to AAO/SnO<sub>2</sub>/a-MoS<sub>2</sub> composite electrodes featuring an amorphous (a-SnO<sub>2</sub>, green) or crystalline (c-SnO<sub>2</sub>, blue) tin oxide underlayer. (a) Cyclic voltammograms, measured from +0.2 V to −0.7 V (vs. SHE). Scan rate 50 mV s<sup>−1</sup>, step size 2 mV. (b) Average steady-state current densities vs. applied potential for AAO/SnO<sub>2</sub>/a-MoS<sub>2</sub> composite electrodes. The electrodes feature pore lengths of 8.6 μm and film thicknesses of 10 nm SnO<sub>2</sub> and 40 c of MoS<sub>2</sub>. Macroscopic electrode area 0.0314 cm<sup>2</sup>, performed in 0.1 M H<sub>2</sub>SO<sub>4</sub> electrolyte.



**Fig. 7** Influence of  $\text{SnO}_2$  crystallinity on the stability of  $\text{AAO}/\text{SnO}_2/\text{a-MoS}_2$  composite electrodes. All electrodes feature pore lengths of  $8.6\ \mu\text{m}$  and  $10\ \text{nm}$  of  $\text{SnO}_2$  and  $\text{MoS}_2$ . Cyclic voltammograms for electrodes with an as-deposited a- $\text{SnO}_2$  coating (purple, a–d) and with annealed c- $\text{SnO}_2$  (cyan, e–h) are characterized at different points of the electrochemical measurement sequence: (a, e) before electrolysis, (b, f) after 1 h at an  $-0.35\ \text{V}$  (vs. SHE), (c, g) after another 1 h at  $-0.40\ \text{V}$ , (d, h) after a final 1 h at  $-0.45\ \text{V}$ . Scan rate  $50\ \text{mV s}^{-1}$ , step size  $2\ \text{mV}$ , electrode area  $0.0314\ \text{cm}^2$ . Performed in  $0.1\ \text{M H}_2\text{SO}_4$  electrolyte. Not only does the annealed  $\text{SnO}_2$  underlayer give rise to a slightly improved performance, it also improves the stability very significantly.

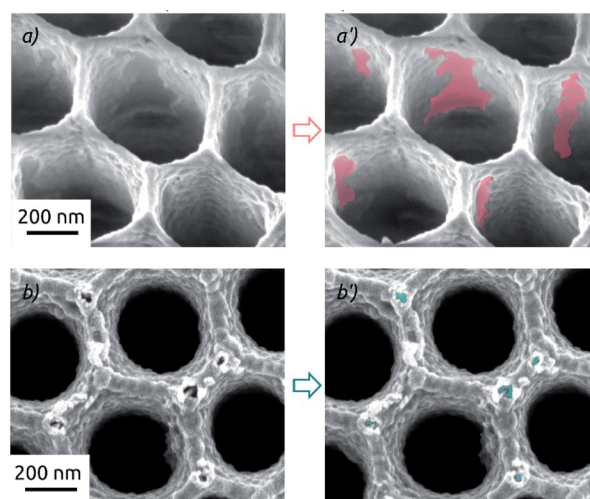
further proven by the poor activity of the  $\text{MoS}_2$ -coated samples bereft of  $\text{SnO}_2$ .

Nanostructured electrodes having c- $\text{SnO}_2$  in direct contact with the electrolyte feature a very characteristic voltammetric pair of waves at  $-0.33\ \text{V}$  and  $-0.23\ \text{V}$  associated with the corrosion of  $\text{SnO}_2$ . The absence of these peaks in CVs for electrodes with an  $\text{AAO}/\text{SnO}_2/\text{a-MoS}_2$  composition indicates that  $\text{MoS}_2$  perfectly covers the entire electrode with a continuous, pinhole-free layer, and thereby prevents  $\text{SnO}_2$  corrosion in the electrolyte, at least initially.

Let us now characterize the stability of  $\text{MoS}_2$ -based electrodes upon steady-state electrolysis. The experiment reported on in Fig. 7 consists in a series of electrolyses, each 60 minutes long, at increasingly negative potentials. One CV is presented before electrolysis (Fig. 7a/e), after an hour at  $-0.35\ \text{V}$  (Fig. 7b/f), after an additional hour at  $-0.40\ \text{V}$  (Fig. 7c/g), and finally after the last hour at  $-0.45\ \text{V}$  (Fig. 7d/h). The evolution of the CV curve shapes is very different for the  $\text{MoS}_2$  electrode on a- $\text{SnO}_2$  (Fig. 7a–d) and on c- $\text{SnO}_2$  (Fig. 7e–h). The poor performance of the former is matched by its poor stability. The characteristic signals of  $\text{SnO}_2$ , which are absent from the pristine sample's data (Fig. 7a), appear immediately upon electrolysis (Fig. 7b). The c- $\text{SnO}_2/\text{a-MoS}_2$  sample, however, remains perfectly stable up to  $-0.40\ \text{V}$  (Fig. 7g), and only the relatively harsh potential  $-0.45\ \text{V}$  proves to be deleterious for it (Fig. 7h, in  $0.1\ \text{M H}_2\text{SO}_4$ ).

This drastic difference in the long-term behavior of samples prepared on a- $\text{SnO}_2$  and c- $\text{SnO}_2$  is highly reproducible. Its cause is apparent in scanning electron microscopic investigation of samples after the full 4 h of electrolysis stability investigation (Fig. 8). Both samples exhibit changes of the surface morphology after

electrochemistry (see also Fig. 2a for comparison). Both samples experience a significant roughening, but the adhesion between  $\text{MoS}_2$  and the underlying  $\text{SnO}_2$  is profoundly different. On a- $\text{SnO}_2$  (Fig. 8a), large areas of oxide have lost their  $\text{MoS}_2$  cover and are apparent. In other words, the  $\text{MoS}_2$  must have detached (areas highlighted in the micrograph). The  $\text{MoS}_2$  on the crystalline layer behaves much better: it maintains its continuity, apart from the appearance of individual, narrow corrosion pits at the protruding edges of



**Fig. 8** Scanning electron micrographs of macroporous electrodes after electrochemical HER (total 4 h at different applied overpotentials) featuring different layer compositions: (a and a')  $\text{AAO}/\text{a-SnO}_2/\text{a-MoS}_2$  ( $10\ \text{nm}$  as-deposited  $\text{SnO}_2$ ). (b and b')  $\text{AAO}/\text{c-SnO}_2/\text{a-MoS}_2$  ( $10\ \text{nm}$  annealed  $\text{SnO}_2$ ). All electrodes feature  $40\ \text{c}$  of  $\text{MoS}_2$ , electrochemistry performed in  $0.1\ \text{M H}_2\text{SO}_4$ .



the nanostructured surface (highlighted in Fig. 8b). These observations are perfectly in line with the contrasting stabilities observed in our electrochemical study. They indicate that the adhesion of MoS<sub>2</sub> is significantly enhanced by the crystalline substrate.

## Conclusions

In conclusion, we establish a model electrode system in which not only the performance of MoS<sub>2</sub> as an electrocatalyst but also its stability can be studied systematically as they depend on the chemical identity, crystallinity, and geometrical features of the porous substrate. The importance of an electrically conductive substrate is confirmed by the linear shape of cyclic voltammograms, which justifies the use of SnO<sub>2</sub> as the substrate. The a-MoS<sub>2</sub> deposited by ALD generates a perfectly continuous coating as soon as the layer thickness reaches a nominal value of 10 nm.

The performance of our samples can be quantified by the overpotential  $-0.25$  V needed to reach  $10 \text{ mA cm}^{-2}$  in  $0.1 \text{ M H}_2\text{SO}_4$ , or  $-0.22$  V in  $0.5 \text{ M H}_2\text{SO}_4$  (values without any internal resistance compensation). The corresponding loading of amorphous MoS<sub>2</sub> is  $0.16 \text{ mg cm}^{-2}$ . Both of these values are comparable to the best featured in the literature (Table S2†).<sup>9,11,40–46</sup> What the system presented here offers as a significant advantage is its control over the electrocatalyst stability. The agreement in the MoS<sub>2</sub> electrocatalysis community is that a-MoS<sub>2</sub> yields the best performance and c-MoS<sub>2</sub> the best stability. Our proposal is that a-MoS<sub>2</sub> on an appropriate crystalline surface such as c-SnO<sub>2</sub> combines both advantageous properties—in addition to the electrical conductivity that is also required simultaneously.

Perhaps most importantly, we contend that this strategy might be of interest beyond the specific materials system studied here. Indeed, adhesion is an issue inherently associated with all 2D materials and represents a significant limitation as soon as bubbles of gaseous products generated by electrolysis impose mechanical constraints on the surface.<sup>47,48</sup> This approach could further enhance the interest in transition metal dichalcogenide electrocatalysts, its generality remains however to be tested.

## Author contributions

JE and YC performed most of the investigation and wrote the original draft. SB provided SEM data and MKSB provided XPS data. EAQ and SC provided the Mo precursor and contributed to manuscript review. JB contributed conceptualization and manuscript review and editing. JE, YC and JB performed data curation.

## Conflicts of interest

There are no conflicts to declare.

## Acknowledgements

This research was funded by the DFG Cluster of Excellence “Engineering of Advanced Materials”, the European Research Council (ERC Consolidator Grant “Solacylin”, grant agreement 647281), and the German Federal Ministry of Education and Research (BMBF project “ECO<sub>2</sub>nvert”, 031B0870B). Y. Y. Cao thanks the China Scholarship Council for the scholarship. EAQ and SC gratefully acknowledge the support by the tutelles of UMR 5265 C2P2 now part of UMR 5128 CP2M (CNRS, CPE Lyon and Université de Lyon 1) and the Nanochemistry platform therein.

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